

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	197819	non\$1volatile or (GMR or (giant adj3 mageto\$1resistiv\$2))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/02 10:11
L2	163	1 near5 (inverter or (pmos adj3 nmos))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/02 10:21
L4	9	2 near10 (generat\$3 or (delay adj3 nand))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/02 10:21
L5	124	1 same (inverter or (pmos adj3 nmos) or transistor) same ((generat\$2 adj3 circuit) or (delay same NAND))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/02 10:23
L6	68	5 and "365"/\$7.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/02 10:31
L8	452	memory near5 (GMR or (gain near5 magneto\$1resistive))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/02 10:44
L12	54	8 same (pre\$1select\$3 or select\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/02 10:50
L13	9	12 same (supply or power or potential or voltage)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/02 10:50

L15	157	8 and 365/226,158.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/02 10:49
L16	150	15 and (supply or power or potential or voltage)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/02 10:50
L17	134	16 and (pre\$1select\$3 or select\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/02 10:57
L18	9	"6178111"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/02 11:05
L19	45	lu-yong.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/02 11:10
L20	0	katti-romney.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/02 11:10
L21	26	katti-romney-r.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/02/02 11:15